

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHCV374FK

Octal Schmitt D-Type Flip Flop with 3-State Output

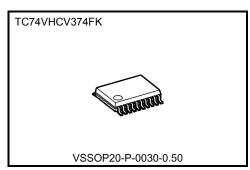
The TC74VHCV374FK is an advanced high speed CMOS OCTAL FLIP-FLOP with 3-STATE OUTPUT fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This 8-bit D-type flip-flop is controlled by a clock input (CK) and an output enable input ($\overline{\rm OE}$).

When the \overline{OE} input is high, the eight outputs are in a high impedance state. Input pin have hysteresis between the positive-going and negative-going thresholds. Thus the TC74VHCV374FK are capable of squaring up transitions of slowly changing input signals and provides an improved noise immunity.

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output $^{(Note)}$ pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

Note: Output in off-state



Weight VSSOP20-P-0030-0.50 : 0.03 g (typ.)

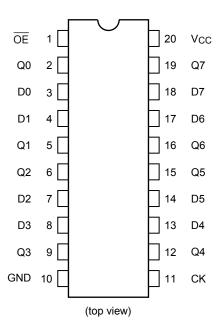
Features

- High speed: fmax = 185 MHz (typ.) at Vcc = 5 V
- Low power dissipation: ICC = 2 μA (max) at Ta = 25°C
- Wide operating voltage range: VCC (opr) = 1.8 V to 5.5 V
- Ouput current: |IOH|/IOL = 16 mA (min) (VCC = 4.5 V)
- Available in VSSOP (US)
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 374 typ

Start of commercial production 2010-01



Pin Assignment



Truth Table

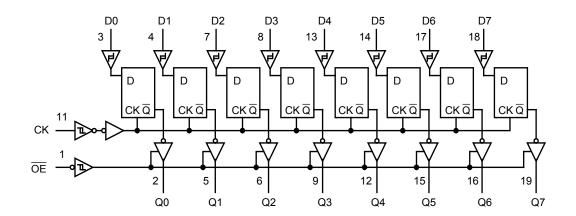
	Inputs	Output			
ŌĒ	CK	D	Output		
Н	Х	Х	Z		
L	\neg	Х	Qn		
L		L	L		
L		Н	Н		

X: Don't care

Z: High impedance

Qn: No change

System Diagram





Absolute Maximum Ratings (Note1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	−0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	V
DC output voltage	V	-0.5 to 7.0 (Note 2)	V
DC output voltage	Vout	-0.5 to V _{CC} + 0.5 (Note 3)	V
Input diode current	lıĸ	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	PD	180	mW
DC V _{CC} /ground current	ICC/IGND	±100	mA
Storage temperature	T _{stg}	−65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in off-state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: VOUT < GND, VOUT > VCC

Operating Ranges (Note1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	Vcc	1.8 to 5.5	٧
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	\/a	0 to 5.5 (Note 2)	V
Output voltage	Vout	0 to V _{CC} (Note 3)	V
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 20 (V _{CC} = 3.3 ± 0.3 V) 0 to 1(V _{CC} = 5 ± 0.5 V)	ms/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

Note 2: Output in off-state Note 3: High or low state.



Electrical Characteristics

DC Characteristics

Characteristics	Test Condition		Ta = 25°C		Ta = −40 to 85°C		Unit			
				VCC (V)	Min	Тур.	Max	Min	Max	
				1.8	_	_	1.65	_	1.65	
				2.3	_	_	1.85	_	1.85	
Positive threshold voltage	VP		_	3.0	_	_	2.20	_	2.20	
				4.5	_	_	3.15	_	3.15	
				5.5		_	3.85	_	3.85	V
				1.8	0.15	_	_	0.15	_	v
Namativa thusahald				2.3	0.45	_	_	0.45	_	
Negative threshold voltage	VN		_	3.0	0.90	_	_	0.90	_	
19				4.5	1.35	_	_	1.35	_	
				5.5	1.65	_	_	1.65	_	
		_		1.8	0.15	_	1.05	0.15	1.05	V
	VH			2.3	0.20	_	1.10	0.20	1.10	
Hysteresis voltage				3.0	0.30	_	1.20	0.30	1.20	
				4.5	0.40	_	1.40	0.40	1.40	
				5.5	0.50	_	1.60	0.50	1.60	
	Vон	VIN = VIH or VIL	I _{OH} = -50 μA	1.8	1.7	1.8	_	1.7	_	
				3.0	2.9	3.0	_	2.9	_	
High-level output voltage				4.5	4.4	4.5	_	4.4	_	
			$I_{OH} = -8 \text{ mA}$	3.0	2.58	_	_	2.48	_	
			I _{OH} = −16 mA	4.5	3.94	_	_	3.80	_	V
				1.8	_	0.0	0.1	_	0.1	V
			IOL = 50 μA	3.0	_	0.0	0.1	_	0.1	-
Low-level output voltage	VoL	V _{IN}		4.5	_	0.0	0.1	_	0.1	
		= V _{IH} or V _{IL}	I _{OL} = 8 mA	3.0		_	0.36	_	0.44	
			I _{OL} = 16 mA	4.5	_		0.44	_	0.55	
3-state output off-state current	loz	VIN = VIH or VIL VOUT = 0 to 5.5V		1.8 to 5.5	_	_	±0.5	_	±5.0	μА
Power-off leakage current	loff	V _{IN} /V _{OUT} = 5.5 V		0		_	0.5	_	5.0	μА
Input leakage current	liN	V _{IN} = 5.5 V d	or GND	0 to 5.5	_	_	±0.1	_	±1.0	μА
Quiescent supply current	Icc	V _{IN} = V _{CC} or	GND	5.5	_	_	2.0	_	20.0	μА



Timing Requirements (input: tr = tf = 3 ns)

Characteristics	Symbol	Test Condition	Ta = 25°C		Ta = -40 to 85°C	Unit	
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width	t (11)		2.5 ± 0.2	_	6.0	7.0	
(CK)	tw (H)	_	3.3 ± 0.3	_	5.0	5.5	ns
(CK)	t _{w (L)}		5.0 ± 0.5	_	5.0	5.0	
	ts		2.5 ± 0.2	_	5.0	5.5	
Minimum set-up time		_	3.3 ± 0.3	_	4.5	4.5	ns
			5.0 ± 0.5	_	3.0	3.0	
	th		2.5 ± 0.2	_	2.5	2.5	
Minimum hold time		_	3.3 ± 0.3	_	2.0	2.0	ns
			5.0 ± 0.5	I	2.0	2.0	



AC Characteristics (input: tr = tf = 3 ns)

Characteristics	Symbol	Tes	est Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
	- ,		V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	5 1t
			2.5 ± 0.2	15	_	12.1	16.3	1.0	19.0	-
				50	_	14.9	19.3	1.0	23.0	
Propagation delay time	tpLH			15		7.1	12.7	1.0	15.0	
(CK-Q)	t _{pHL}	_	3.3 ± 0.3	50	_	9.2	16.2	1.0	18.5	ns
, ,				15		5.4	8.1	1.0	9.5	
			5.0 ± 0.5	50	_	7.1	10.1	1.0	11.5	
				15	_	9.4	15.9	1.0	19.0	
			2.5 ± 0.2	50	_	12.3	18.8	1.0	22.0	
3-state output enable	t_{pZL}	D 410	00.00	15	_	6.5	11.0	1.0	13.0	
time	t _{pZH}	R _L = 1 kΩ	3.3 ± 0.3	50	1	8.7	14.5	1.0	16.5	ns
			5.0 ± 0.5	15	_	4.5	7.6	1.0	9.0	
				50	_	6.2	9.6	1.0	11.0	
	t _{pLZ} t _{pHZ}	R _L = 1 kΩ	2.5 ± 0.2	50	_	14.5	17.3	1.0	19.0	ns
3-state output disable time			3.3 ± 0.3	50	_	10.9	14.0	1.0	16.0	
			5.0 ± 0.5	50	_	8.0	8.8	1.0	10.0	
			2.5 ± 0.2	15	60	80	_	50	_	- MHz
				50	50	65	_	40	_	
Maximum clock	f		3.3 ± 0.3	15	80	140	_	70	_	
frequency	f _{max}	_	3.3 ± 0.3	50	55	105	_	50	_	IVII IZ
			5.0 ± 0.5	15	130	185	_	110	_	
			3.0 ± 0.5	50	85	140	_	75	_	
	4		2.5 ± 0.2	50	1	_	2.0	-	2.0	
Output to output skew	t _{osLH} t _{osHL}	(Note 1)	3.3 ± 0.3	50	_	_	1.5	_	1.5	ns
	405⊓L		5.0 ± 0.5	50	_	_	1.0	_	1.0	
Input capacitance	C _{IN}		_		_	4	10	_	10	pF
Output capacitance	Cout		_		-	6	_	_	_	pF
Power dissipation capacitance	C _{PD}			(Note 2)	-	21	_	_	_	pF

Note 1: Parameter guaranteed by design.

tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|

Note 2: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $ICC (opr) = CPD \cdot VCC \cdot fIN + ICC/8 (per F/F)$

And the total CPD when n pcs. of latch operate can be gained by the following equation:

CPD (total) = 11+ 10·n



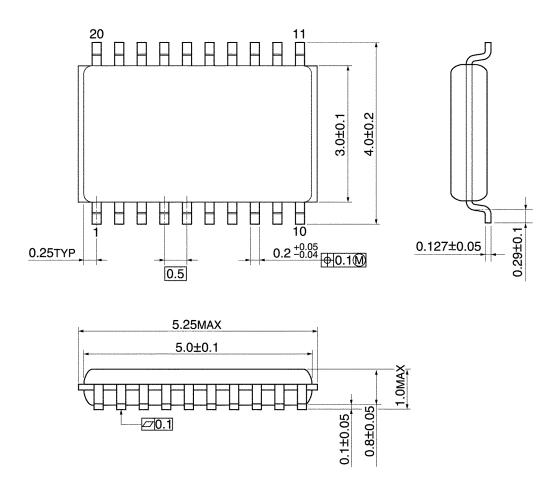
Noise Characteristics (input: tr = tf = 3 ns)

Charactaristics	Currente ed	Test Condition		Ta = 25°C		1.124
Characteristics	Symbol		V _{CC} (V)	Тур.	Max	Unit
Quiet output maximum dynamic V _{OL}	Vola	C _I = 50 pF	3.3	0.3	_	V
Quiet output maximum dynamic vol	V_{OLP}	CL = 50 pr	5.0	0.7	_	
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	3.3	-0.1	_	V
Quiet output minimum dynamic VOL			5.0	-0.4	_	V
Minimum high level dynamic input voltage	VIHD	C _L = 50 pF	5.0	_	3.5	V
Maximum low level dynamic input voltage	VILD	C _L = 50 pF	5.0	_	1.5	V



Package Dimensions

VSSOP20-P-0030-0.50 Unit: mm



Weight: 0.03 g (typ.)



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